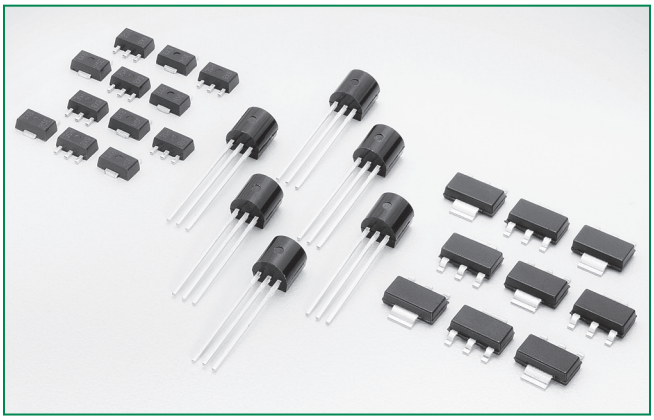
Teccor® brand Thyristors
EV Series 0.8 Amp Sensitive SCRs

SxX8xSx Series

HF RoHS



Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	0.8	A
V_{DRM}/V_{RRM}	400 to 800	V
I_{GT}	5 to 200	µA

Applications

The SxX8xSx EV series is specifically designed for GFCI (Ground Fault Circuit Interrupter) and gas ignition applications.

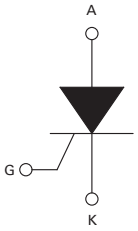
Description

New device series offers high static dv/dt and lower turn off (t_q) sensitive SCR with its small die planar construction design. It is specifically designed for GFCI (Ground Fault Circuit Interrupter) and Gas Ignition applications. All SCRs junctions are glass-passivated to ensure long term reliability and parametric stability.

Features

- RoHS compliant and Halogen-Free
- Thru-hole and surface mount packages
- Surge current capability > 10Amps
- Blocking voltage (V_{DRM}/V_{RRM}) capability - up to 800V
- High dv/dt noise immunity
- Improved turn-off time (t_q) < 25 µsec
- Sensitive gate for direct microprocessor interface

Schematic Symbol



Absolute Maximum Ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TO-92	T_C = 55°C	0.8	A
		SOT-89	T_C = 60°C	0.8	A
		SOT-223	T_L = 60°C	0.8	A
$I_{T(AV)}$	Average on-state current	TO-92	T_C = 55°C	0.51	A
		SOT-89	T_C = 60°C	0.51	A
		SOT-223	T_L = 60°C	0.51	A
I_{TSM}	Non repetitive surge peak on-state current (Single cycle, T_J initial = 25°C)	TO-92 SOT-89 SOT-223	F= 50Hz	8	A
			F= 60Hz	10	A
I^2t	I^2t Value for fusing	t_p = 10 ms	F = 50 Hz	0.32	A^2s
		t_p = 8.3 ms	F = 60 Hz	0.41	A^2s
di/dt	Critical rate of rise of on-state current I_G = 10mA	TO-92 SOT-89 SOT-223	T_J = 125°C	50	A/µs
I_{GM}	Peak Gate Current	t_p = 10 µs	T_J = 125°C	1.0	A
$P_{G(AV)}$	Average gate power dissipation	—	T_J = 125°C	0.1	W
T_{stg}	Storage junction temperature range	—	—	-40 to 150	°C
T_J	Operating junction temperature range	—	—	-40 to 125	°C

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Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value			Unit
				SxX8yS1	SxX8yS2	SxX8yS	
I_{GT}	DC Gate Trigger Current	V_D = 6V R_L = 100 Ω	MIN.	0.5	1	15	µA
			MAX.	5	50	200	µA
V_{GT}	DC Gate Trigger Voltage	V_D = 6V R_L = 100 Ω	MAX.	0.8			V
V_{GRM}	Peak Reverse Gate Voltage	I_{RG} = 10µA	MIN.	5			V
I_H	Holding Current	R_{GK} = 1 KΩ Initial Current = 20mA	MAX.	5			mA
(dv/dt)s	Critical Rate-of-Rise of Off-State Voltage	T_J = 125°C $V_D = V_{DRM}/V_{RRM}$ Exp. Waveform R_{GK} =1 kΩ	MIN.	75			V/µs
V_{GD}	Gate Non-Trigger Voltage	$V_D = V_{DRM}$ R_{GK} =1 kΩ T_J = 25°C	MIN.	0.2			V
t_q	Turn-Off Time	T_J = 25°C @ 600 V R_{GK} =1 kΩ	MAX.	30	25	25	µs
t_{gt}	Turn-On Time	I_G=10mA PW = 15µsec I_T = 1.6A(pk)	TYP.	2.0	2.0	2.0	µs

Note: x = voltage, y = package

Static Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value	Unit
V_{TM}	Peak On-State Voltage	I_{TM} = 1.6A (pk)	MAX.	1.70	V
I_{DRM}	Off-State Current, Peak Repetitive	T_J = 25°C @ $V_D = V_{DRM}$ R_{GK} =1 kΩ	MAX.	3	µA
		T_J = 125°C @ VD = V_{DRM} R_{GK} =1 kΩ	MAX.	500	µA

Thermal Resistances

Symbol	Description	Test Conditions		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	$I_T = 0.8A_{(RMS)}$ [1]	TO-92	75	°C/W
			SOT-223	30	°C/W
			SOT-89	50	°C/W
$R_{th(j-a)}$	Junction to ambient	$I_T = 0.8A_{(RMS)}$ [1]	TO-92	150	°C/W
			SOT-223	60	°C/W
			SOT-89	90	°C/W

[1] 60Hz AC resistive load condition, 100% conduction.

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Figure 1: Normalized DC Gate Trigger Current For All Quadrants vs. Junction Temperature

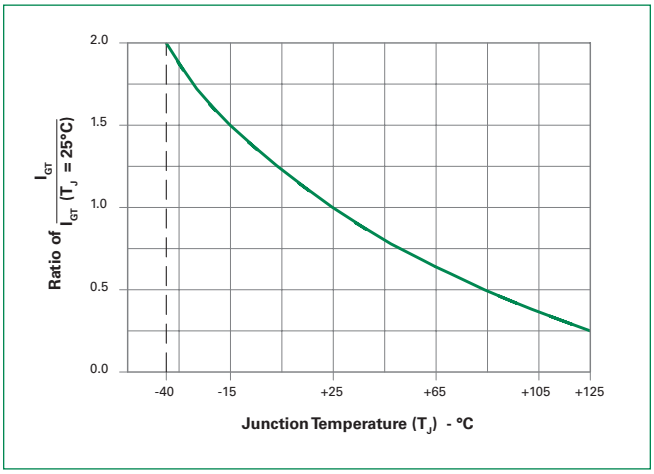

Figure 2: Normalized DC Holding Current vs. Junction Temperature

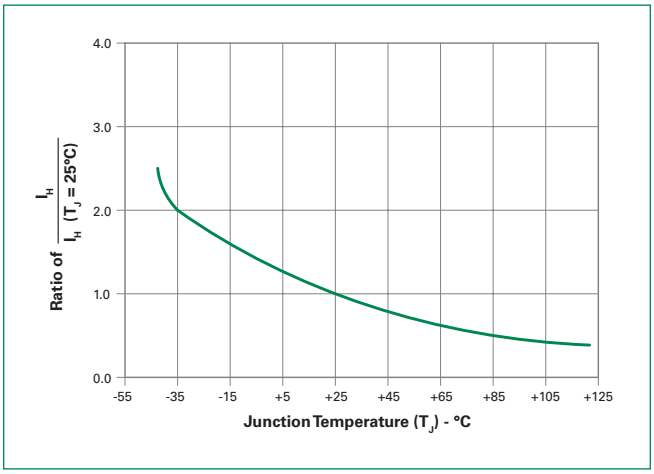

Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature

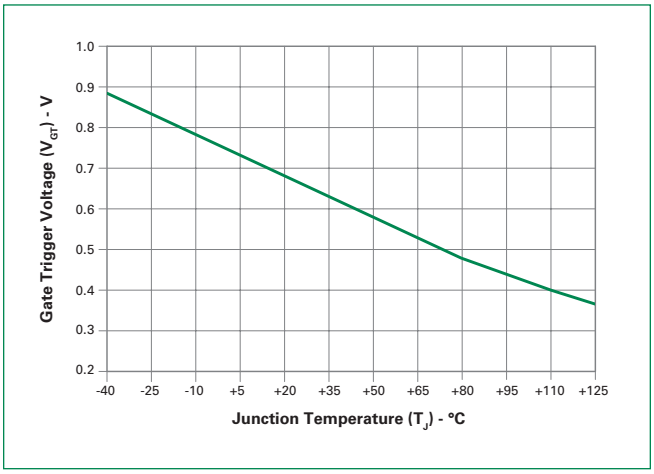

Figure 4: Power Dissipation (Typical) vs. RMS On-State Current

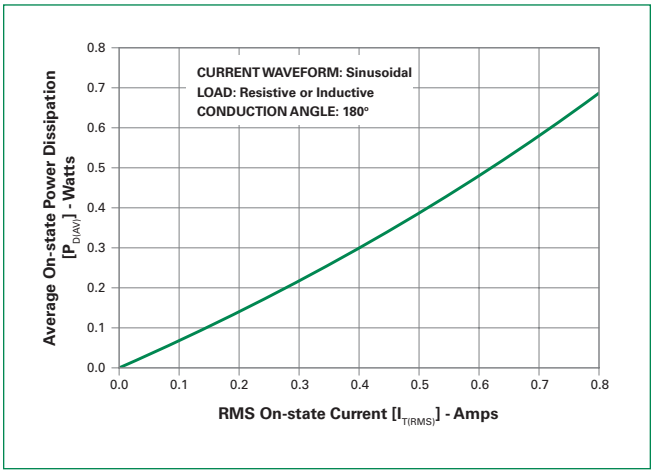

Figure 5: Maximum Allowable Case Temperature vs. On-State Current

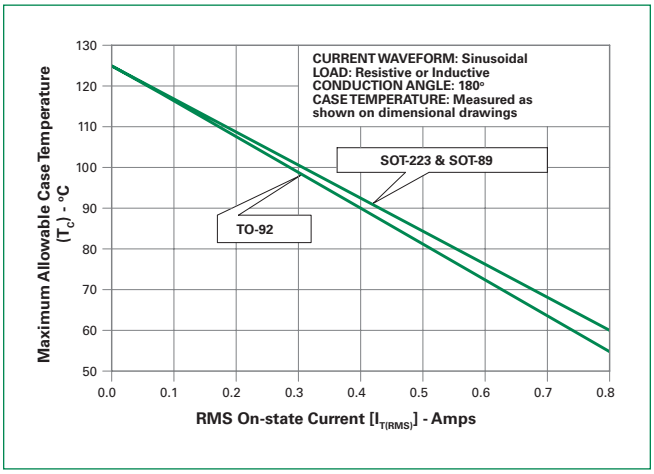

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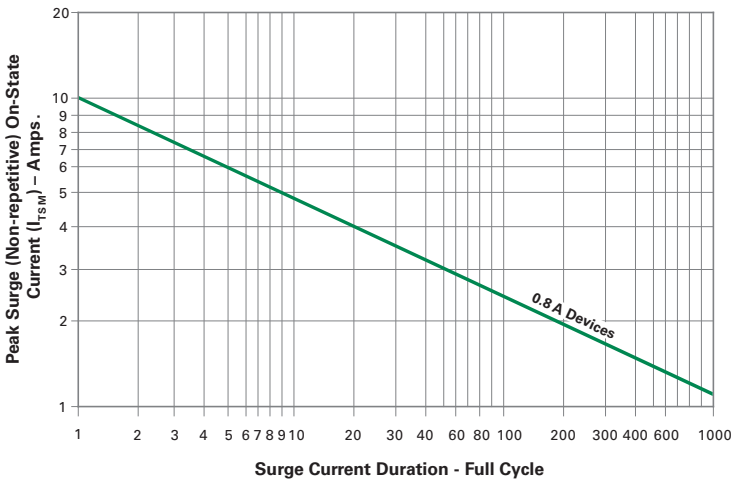
Figure 6: Surge Peak On-State Current vs. Number of Cycles

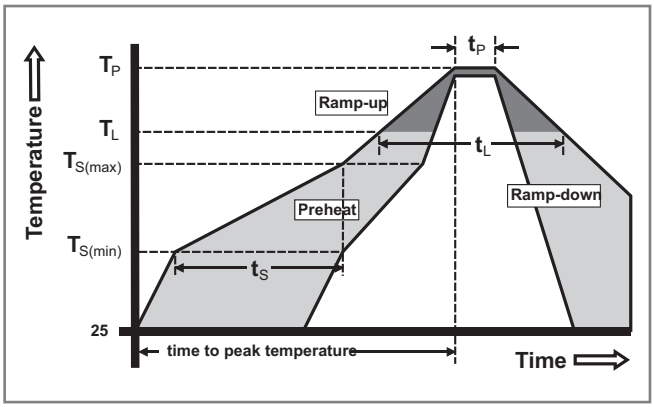


Supply Frequency: 60Hz Sinusoidal
Load: Resistive
RMS On-State Current [$I_{T(RMS)}$]: Max Rated Value at Specific Case Temperature

Notes:
1. Gate control may be lost during and immediately following surge current interval.
2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	-Temperature Min ($T_{s(min)}$)	150°C
	-Temperature Max ($T_{s(max)}$)	200°C
	-Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	-Temperature (T_L) (Liquidus)	217°C
	-Time (min to max) (t_s)	60 – 150 seconds
Peak Temperature (T_P)		$260^{+0/-5}$ °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C



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Physical Specifications

Terminal Finish	100% Matte Tin-plated.
Body Material	UL recognized epoxy meeting flammability classification 94V-0.
Lead Material	Copper Alloy

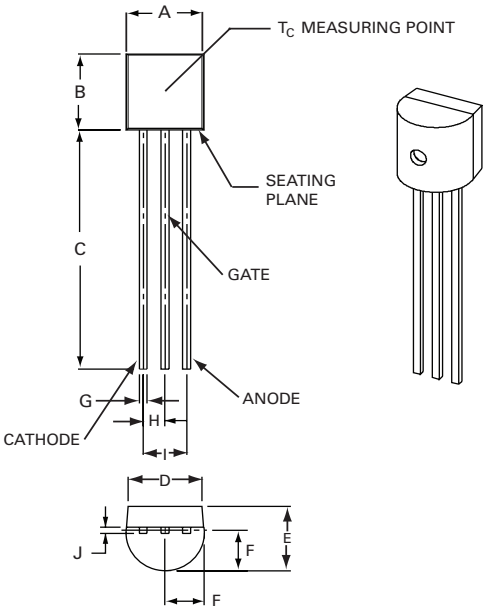
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell-time at each temperature; 10 sec (max) transfer time between temperature
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

Dimensions – TO-92



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.175	0.205	4.450	5.200
B	0.170	0.210	4.320	5.330
C	0.500		12.70	
D	0.135		3.430	
E	0.125	0.165	3.180	4.190
F	0.080	0.105	2.040	2.660
G	0.016	0.021	0.407	0.533
H	0.045	0.055	1.150	1.390
I	0.095	0.105	2.420	2.660
J	0.015	0.020	0.380	0.500

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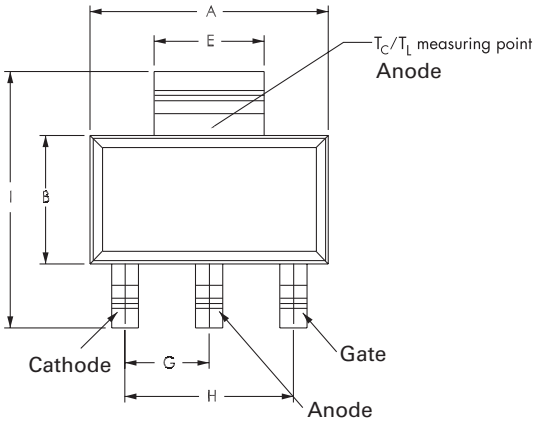
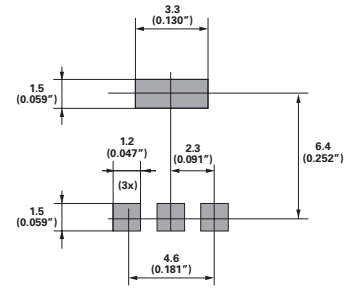
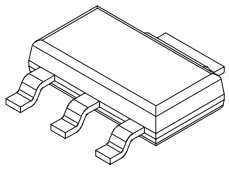
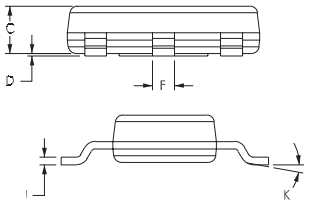
Dimensions – SOT-223





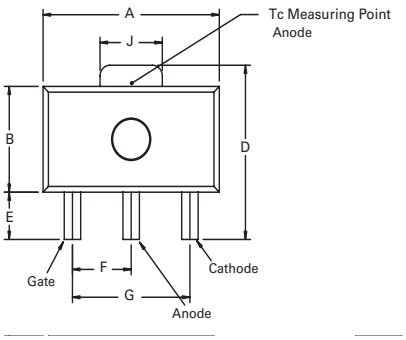
Dimensions in Millimeters (Inches)



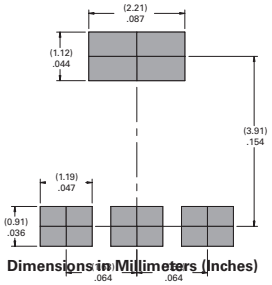


Dimensions	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.248	0.256	0.264	6.30	6.50	6.70
B	0.130	0.138	0.146	3.30	3.50	3.70
C	—	—	0.071	—	—	1.80
D	0.001	—	0.004	0.02	—	0.10
E	0.114	0.118	0.124	2.90	3.00	3.15
F	0.024	0.027	0.034	0.60	0.70	0.85
G	—	0.090	—	—	2.30	—
H	—	0.181	—	—	4.60	—
I	0.264	0.276	0.287	6.70	7.00	7.30
J	0.009	0.010	0.014	0.24	0.26	0.35
K	10° MAX					

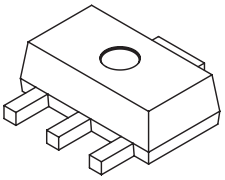
Dimensions – SOT-89

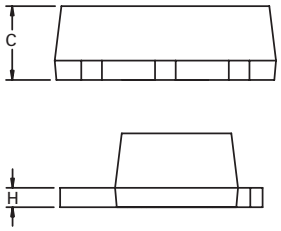


Pad Layout for SOT-89



Dimensions in Millimeters (Inches)





Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.173	—	0.181	4.40	—	4.60
B	0.090	—	0.102	2.29	—	2.60
C	0.055	—	0.063	1.40	—	1.60
D	0.155	—	0.167	3.94	—	4.25
E	0.035	—	0.047	0.89	—	1.20
F	0.056	—	0.062	1.42	—	1.57
G	0.115	—	0.121	2.92	—	3.07
H	0.014	—	0.017	0.35	—	0.44
I	0.014	—	0.019	0.36	—	0.48
J	0.064	—	0.072	1.62	—	1.83

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Product Selector

Part Number	Voltage			Gate Sensitivity	Package
	400V	600V	800V		
S4X8ES	X	—	—	200 µA	TO-92
S6X8ES	—	X	—	200 µA	TO-92
S8X8ES	—	—	X	200 µA	TO-92
S4X8TS	X	—	—	200 µA	SOT-223
S6X8TS	—	X	—	200 µA	SOT-223
S8X8TS	—	—	X	200 µA	SOT-223
S4X8BS	X	—	—	200 µA	SOT-89
S6X8BS	—	X	—	200 µA	SOT-89
S4X8ES1	X	—	—	5 µA	TO-92
S6X8ES1	—	X	—	5 µA	TO-92
S8X8ES1	—	—	X	5 µA	TO-92
S4X8TS1	X	—	—	5 µA	SOT-223
S6X8TS1	—	X	—	5 µA	SOT-223
S8X8TS1	—	—	X	5 µA	SOT-223
S4X8ES2	X	—	—	50 µA	TO-92
S6X8ES2	—	X	—	50 µA	TO-92
S8X8ES2	—	—	X	50 µA	TO-92
S4X8TS2	X	—	—	50 µA	SOT-223
S6X8TS2	—	X	—	50 µA	SOT-223
S8X8TS2	—	—	X	50 µA	SOT-223

Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
SxX8ESy	SxX8ESy	0.170g	Bulk	2500
SxX8ESyAP	SxX8ESy	0.170g	Ammo Pack	2000
SxX8ESyRP	SxX8ESy	0.170g	Tape & Reel	2000
SxX8TSyRP	SxX8TSy	0.120g	Tape & Reel	1000
SxX8BSRP	xX8	0.053g	Tape & Reel	1000
SxX8BSRP1	xX8	0.053g	Tape & Reel	1000

Note: x = voltage, y = gate sensitivity

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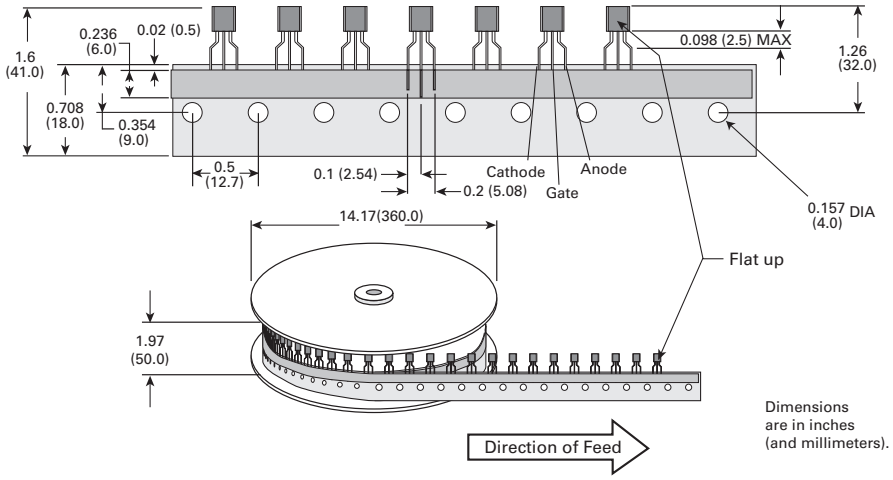
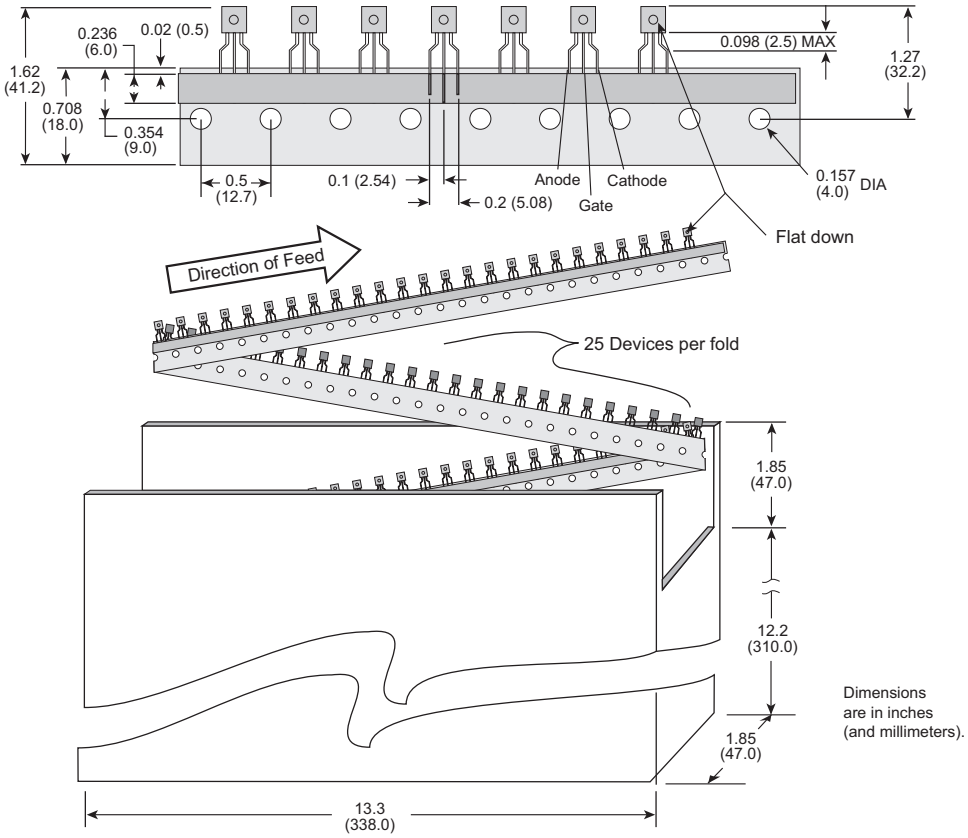
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-C Standards



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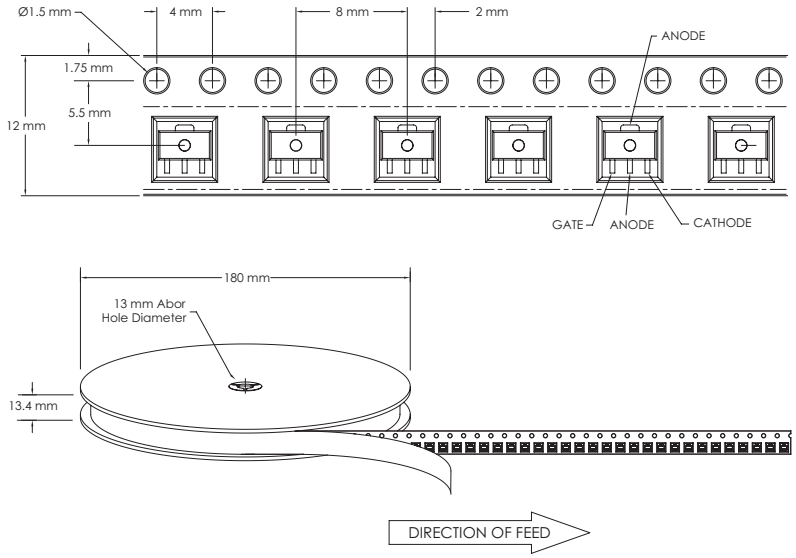
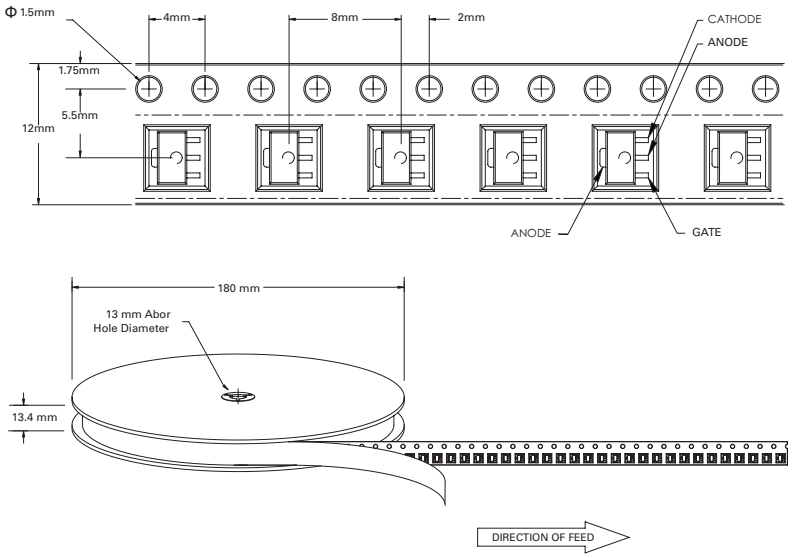
SOT-89 Reel Pack (RP) Specifications



SOT-89 Reel Pack (RP1) Specifications



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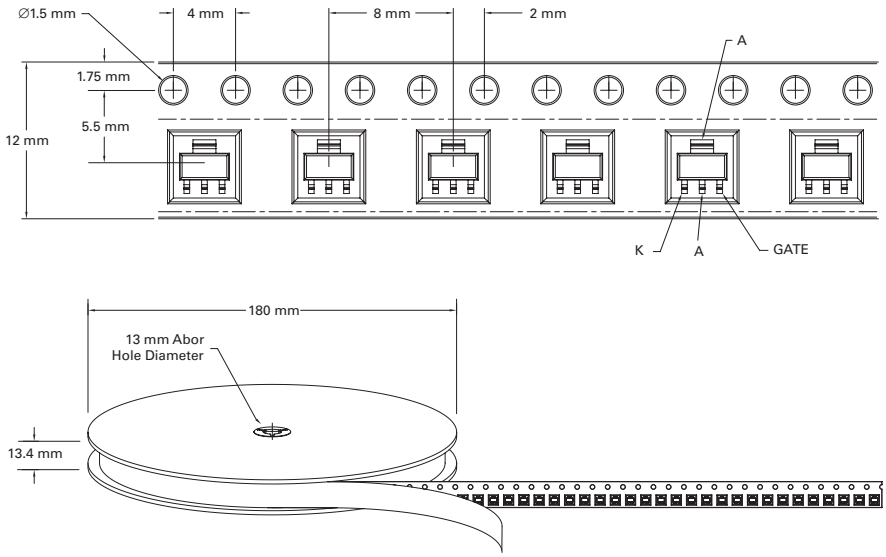
SOT-223 Reel Pack (RP) Specifications



Part Numbering System

S x X8 x xx xx

SERIES
S: SCR

VOLTAGE
4: 400V
6: 600V
8: 800V

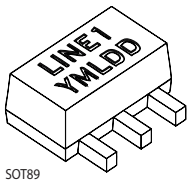
CURRENT
X8: 0.8A

SENSITIVITY & TYPE
S1: 5µA Sensitive SCR
S2: 50µA Sensitive SCR
S: 200µA Sensitive SCR

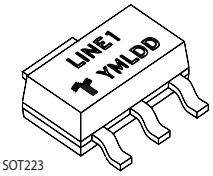
PACKAGE TYPE
E: TO-92
T: SOT-223
B: SOT-89

PACKING TYPE
Blank: Bulk Pack
RP: Reel Pack (TO-92)
Embossed Carrier Pack (SOT-223)
Embossed Carrier Pack (SOT-89)
RP1: Embossed Carrier Pack (SOT-89)
(alternate orientation)
AP: Ammo Pack (TO-92)

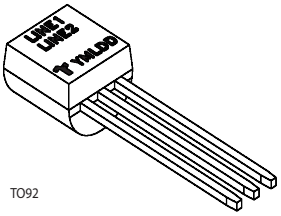
Part Marking System



SOT89



SOT223



TO92

Line1 = Littelfuse Part Number
Line2 = continuation…Littelfuse Part Number
Y = Last Digit of Calendar Year
M = Letter Month Code (A-L for Jan-Dec)
L = Location Code
DD = Calendar Date

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Specifications are subject to change without notice.
Please refer to http://www.littelfuse.com for current information.

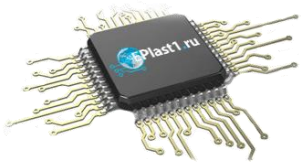
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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